

## PATENT ASSIGNMENT COVER SHEET

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EPAS ID: PAT6211962

<b>SUBMISSION TYPE:</b>	NEW ASSIGNMENT
<b>NATURE OF CONVEYANCE:</b>	ASSIGNMENT
<b>CONVEYING PARTY DATA</b>	
<b>Name</b>	<b>Execution Date</b>
YI-TSE HUNG	07/08/2020
CHAO-CHING CHENG	07/08/2020
TSE-AN CHEN	07/08/2020
HUNG-LI CHIANG	07/08/2020
TZU-CHIANG CHEN	07/08/2020
LAIN-JONG LI	07/08/2020
<b>RECEIVING PARTY DATA</b>	
<b>Name:</b>	Taiwan Semiconductor Manufacturing Co., Ltd.
<b>Street Address:</b>	8, Li-Hsin Rd. 6, Hsinchu Science Park
<b>City:</b>	Hsinchu
<b>State/Country:</b>	TAIWAN
<b>Postal Code:</b>	300-78
<b>PROPERTY NUMBERS Total: 1</b>	
<b>Property Type</b>	<b>Number</b>
Application Number:	16887729
<b>CORRESPONDENCE DATA</b>	
<b>Fax Number:</b>	(972)732-9218
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
<b>Phone:</b>	972-732-1001
<b>Email:</b>	docketing@slatermatsil.com
<b>Correspondent Name:</b>	SLATER MATSIL, LLP
<b>Address Line 1:</b>	17950 PRESTON RD., SUITE 1000
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<b>ATTORNEY DOCKET NUMBER:</b>	TSMP20194052US00
<b>NAME OF SUBMITTER:</b>	VICTORIA DEVRIES
<b>SIGNATURE:</b>	/Victoria DeVries/
<b>DATE SIGNED:</b>	07/21/2020
<b>Total Attachments: 2</b>	

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**PATENT**

**REEL: 053274 FRAME: 0475**

74 (S)  
NP-27232-0-US-B6ATTORNEY DOCKET NO.  
TSMP20194052US00**ASSIGNMENT**

WHEREAS, I, the undersigned inventor (or one of the undersigned joint inventors), of residence as listed, having invented certain new and useful improvements as below entitled, for which application for United States Letters Patent is made; and

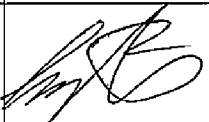

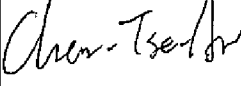
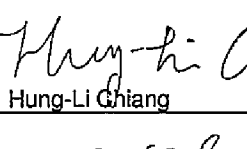
WHEREAS, Taiwan Semiconductor Manufacturing Co., Ltd. ("Assignee"), a corporation organized and existing under the laws of Taiwan, with its principal office at 8, Li-Hsin Rd. 6 Hsinchu Science Park, Hsinchu 300-78, Taiwan, is desirous of acquiring my entire right, title and interest in and to said invention, and to said application and any Letters Patent that may issue thereon in the United States and all other countries throughout the world;

NOW, THEREFORE, for good and valuable consideration, the receipt of which is hereby acknowledged, I hereby sell and assign to said Assignee, its successors and assigns, my entire right, title and interest in and to said invention and in and to said application and all patents which may be granted therefor, and all future non-provisional applications including divisions, reissues, substitutions, continuations, and extensions thereof; and I hereby authorize and request the Commissioner for Patents to issue all patents for said invention, or patent resulting therefrom, insofar as my interest is concerned, to said Assignee, as assignee of my entire right, title and interest. I declare that I have not executed and will not execute any agreement in conflict herewith.

I also hereby sell and assign to Assignee, its successors and assigns, my foreign rights to the invention disclosed in said application, in all countries of the world, including, but not limited to, the right to file applications and obtain patents under the terms of the International Convention for the Protection of Industrial Property, and of the European Patent Convention, and further agree to execute any and all patent applications, assignments, affidavits, and any other papers in connection therewith necessary to perfect such patent rights.

I hereby further agree that I will communicate to said Assignee, or to its successors, assigns, and legal representatives, any facts known to me respecting said invention or the file history thereof, and at the expense of said Assignee, its legal representatives, successors, or assigns, will testify in any legal proceedings, sign all lawful papers, execute all divisional, continuation, reissue and substitute applications, make all lawful oaths, and generally do everything possible to aid said Assignee, its legal representatives, successors, and assigns, to obtain and enforce proper patent protection for said invention in all countries.

IN WITNESS WHEREOF, I hereunto set my hand and seal this day and year;

TITLE OF INVENTION	Fin Field-Effect Transistor Device with Low-Dimensional Material and Method			
SIGNATURE OF INVENTOR AND NAME	 Yi-Tse Hung	 Chao-Ching Cheng	 Tse-An Chen	 Hung-Li Chiang
DATE	070820	2020.07.08	2020.07.08	2020.7.8
RESIDENCE	Hsinchu, Taiwan	Hsinchu, Taiwan	Taoyuan, Taiwan	Taipei, Taiwan

ATTORNEY DOCKET NO.  
TSMP20194052US00

### ASSIGNMENT

WHEREAS, I, the undersigned inventor (or one of the undersigned joint inventors), of residence as listed, having invented certain new and useful improvements as below entitled, for which application for United States Letters Patent is made; and



WHEREAS, Taiwan Semiconductor Manufacturing Co., Ltd. ("Assignee"), a corporation organized and existing under the laws of Taiwan, with its principal office at 8, Li-Hsin Rd. 6 Hsinchu Science Park, Hsinchu 300-78 Taiwan, is desirous of acquiring my entire right, title and interest in and to said invention, and to said application and any Letters Patent that may issue thereon in the United States and all other countries throughout the world;

NOW, THEREFORE, for good and valuable consideration, the receipt of which is hereby acknowledged, I hereby sell and assign to said Assignee, its successors and assigns, my entire right, title and interest in and to said invention and in and to said application and all patents which may be granted therefor, and all future non-provisional applications including divisions, reissues, substitutions, continuations, and extensions thereof; and I hereby authorize and request the Commissioner for Patents to issue all patents for said invention, or patent resulting therefrom, insofar as my interest is concerned, to said Assignee, as assignee of my entire right, title and interest. I declare that I have not executed and will not execute any agreement in conflict herewith.

I also hereby sell and assign to Assignee, its successors and assigns, my foreign rights to the invention disclosed in said application, in all countries of the world, including, but not limited to, the right to file applications and obtain patents under the terms of the International Convention for the Protection of Industrial Property, and of the European Patent Convention, and further agree to execute any and all patent applications, assignments, affidavits, and any other papers in connection therewith necessary to perfect such patent rights.

I hereby further agree that I will communicate to said Assignee, or to its successors, assigns, and legal representatives, any facts known to me respecting said invention or the file history thereof, and at the expense of said Assignee, its legal representatives, successors, or assigns, will testify in any legal proceedings, sign all lawful papers, execute all divisional, continuation, reissue and substitute applications, make all lawful oaths, and generally do everything possible to aid said Assignee, its legal representatives, successors, and assigns, to obtain and enforce proper patent protection for said invention in all countries.

IN WITNESS WHEREOF, I hereunto set my hand and seal this day and year;

TITLE OF INVENTION	Fin Field-Effect Transistor Device with Low-Dimensional Material and Method			
SIGNATURE OF INVENTOR AND NAME	 Tzu-Chiang Chen	 Lain-Jong Li		
DATE	2020.7.8	2020.7.8		
RESIDENCE	Hsinchu, Taiwan	Hsinchu, Taiwan		